

#### INCHANGE SEMICONDUCTOR

## **Isc N-Channel MOSFET Transistor**

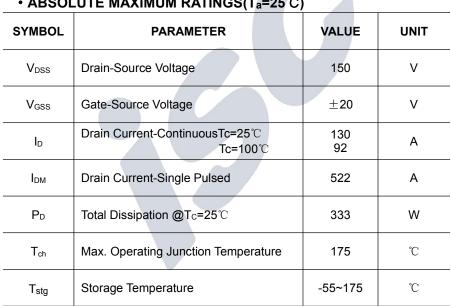
## FDB075N15A

#### FEATURES

- With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

· Switching applications

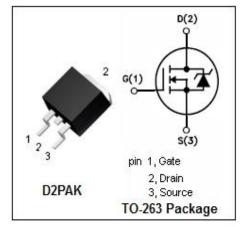


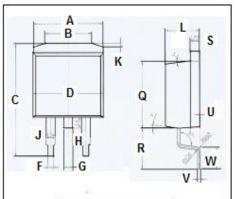
#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

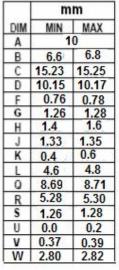
#### THERMAL CHARACTERISTICS

| SYMBOL    | PARAMETER                             |      | UNIT         |  |
|-----------|---------------------------------------|------|--------------|--|
| Rth(ch-c) | Channel-to-case thermal resistance    | 0.45 | °C <b>/W</b> |  |
| Rth(ch-a) | Channel-to-ambient thermal resistance | 62.5 | °C <b>/W</b> |  |

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#### isc website: www.iscsemi.cn

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#### ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

| SYMBOL               | PARAMETER                      | CONDITIONS  | MIN | ТҮР  | МАХ      | UNIT |
|----------------------|--------------------------------|---|-----|------|----------|------|
| BV <sub>DSS</sub>    | Drain-Source Breakdown Voltage | V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA   | 150 |      |          | v    |
| V <sub>GS</sub> (th) | Gate Threshold Voltage         | V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA   | 2.0 |      | 4.0      | V    |
| R <sub>DS(on)</sub>  | Drain-Source On-Resistance     | V <sub>GS</sub> = 10V; I <sub>D</sub> =100A   |     | 6.25 | 7.5      | mΩ   |
| I <sub>GSS</sub>     | Gate-Source Leakage Current    | V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V  |     |      | ±0.1     | μA   |
| I <sub>DSS</sub>     | Drain-Source Leakage Current   | V <sub>DS</sub> =120V; V <sub>GS</sub> = 0V;Tj=25℃<br>V <sub>DS</sub> =120V; V <sub>GS</sub> = 0V;Tj=150℃ |     |      | 1<br>500 | μA   |
| V <sub>SDF</sub>     | Diode forward voltage          | I <sub>SD</sub> =100A, V <sub>GS</sub> = 0 V  |     |      | 1.25     | V    |

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